

#7/3-1-20
Bereskin & Parr

Barristers and Solicitors/Patent and Trade Mark Agents
Practice Restricted to Intellectual Property Law

October 4, 2001

H. Samuel Frost B.A. (Eng. Sci.), M.Sc. (Nucl. Eng.)
416 957 1687 sfrost@bereskinparr.com

Your Reference: 09/833,078
Our Reference: 45-35

Information Disclosure Statement

The Commissioner of Patents
& Trademarks
Box 5
Washington, D.C.
20231
U.S.A.

RECEIVED
OCT -5 2001
TECHNOLOGY CENTER 2800

Dear Sir:

Re: Information Disclosure Statement
U.S. Patent Application No. 09/833,078
Title: A METHOD FOR LOCALLY MODIFYING THE EFFECTIVE BANDGAP
ENERGY IN INDIUM GALLIUM ARSENIDE PHOSPHIDE (InGaAsP)
QUANTUM WELL STRUCTURES
Filed: April 12, 2001
Applicants: THOMPSON et al.

In accordance with 37 C.F.R. 1.97 and 1.98, and in recognition of the duty of disclosure set forth in 37 C.F.R. 1.56, the applicant hereby submits an Information Disclosure Statement including (1) a listing, on PTO Form 1449, of all patents and other publications of which the applicant is aware that may be considered material to the patentability of its claimed invention, and (2) a copy of each listed patent or publication.

Respectfully submitted,

By: 

H. Samuel Frost
Registration No. 31,696

TO/cc
Encl.